



2019년 2월 14일(목), 11:00-12:30

Room D (스타홀, 2층)

[TD2-J] Hybrid Perovskite Materials

좌장: 유승협 교수(KAIST), 이태우 교수(서울대학교)

<p>TD2-J-1 11:00-11:15</p>	<p>Correlating Nano Black Spots and Optical Stability in Inorganic Perovskite CsPbBr_{3-x}I_x Quantum Dot Seo-Yun Kim, Seung-Jae Lee, Ji-Eun Lee, Yun-Hyuk Ko, Mohammed Jalalah, and Jea-Gun Park <i>Advanced Semiconductor Materials and Device Development Center, Hanyang University</i></p>
<p>TD2-J-2 11:15-11:45</p>	<p>[초청] Emerging Memory Devices with Hybrid Materials Jang-Sik Lee <i>Department of Materials Science and Engineering, POSTECH</i></p>
<p>TD2-J-3 11:45-12:00</p>	<p>Concentrating Conductive Paths in Resistive Switching Memory Device via Nanomesh Patterning Tae Jin Kim, Byoung Kuk You, and Keon Jae Lee <i>Department of Material Science and Engineering, KAIST</i></p>
<p>TD2-J-4 12:00-12:15</p>	<p>Large Area, Ultrafast Sub-10 nm Self-assembled Nanopattern by Flash Light with High Flory-Huggins interaction parameter Block copolymer Jang Hwan Kim, Hyeong Min Jin, Dae yong Park, Keon Jae Lee, and Sang Ouk Kim <i>Department of Materials Science and Engineering, KAIST</i></p>
<p>TD2-J-5 12:15-12:30</p>	<p>Edge Contact Length가 그래핀-ZnO배리스터에 미치는 전기적 특성 분석 김민재¹, 김소영², 이용수², 김승모², 이병훈² ¹Chemistry Concentration, ²Center for Emerging Electric Devices and Systems, School of Material Science and Engineering, GIST</p>